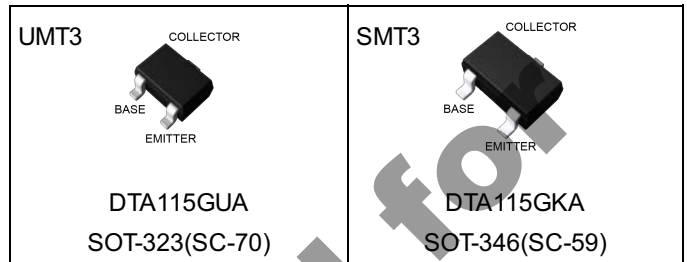


Parameter	Value
$V_{CEO}$	-50V
$I_C$	-100mA
R	100k $\Omega$

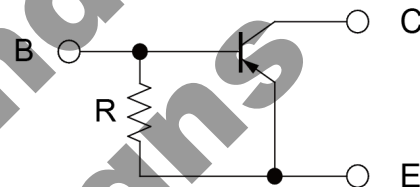
### ●Outline



### ●Features

- 1) Built-In Biasing Resistor
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit) .
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Complementary NPN Types: DTC115G series
- 5) Lead Free/RoHS Compliant.

### ●Inner circuit



B: BASE  
C: COLLECTOR  
E: EMITTER

### ●Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

### ●Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
DTA115GUA	UMT3	2021	T106	180	8	3000	K19
DTA115GKA	SMT3	2928	T146	180	8	3000	K19

● **Absolute maximum ratings** ( $T_a = 25^\circ\text{C}$ )

Parameter		Symbol	Values	Unit
Collector-base voltage		$V_{CBO}$	-50	V
Collector-emitter voltage		$V_{CEO}$	-50	V
Emitter-base voltage		$V_{EBO}$	-5	V
Collector current		$I_C$	-100	mA
Power dissipation	DTA115GUA	$P_D^{*1}$	200	mW
	DTA115GKA		200	
Junction temperature		$T_j$	150	$^\circ\text{C}$
Range of storage temperature		$T_{stg}$	-55 to +150	$^\circ\text{C}$

● **Electrical characteristics** ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector-base breakdown voltage	$BV_{CBO}$	$I_C = -50\mu\text{A}$	-50	-	-	V
Collector-emitter breakdown voltage	$BV_{CEO}$	$I_C = -1\text{mA}$	-50	-	-	V
Emitter-base breakdown voltage	$BV_{EBO}$	$I_E = -72\mu\text{A}$	-5	-	-	V
Collector cut-off current	$I_{CBO}$	$V_{CB} = -50\text{V}$	-	-	-0.5	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -4\text{V}$	-30	-	-58	$\mu\text{A}$
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C / I_B = -5\text{mA} / -0.25\text{mA}$	-	-	-0.3	V
DC current gain	$h_{FE}$	$V_{CE} = -5\text{V}, I_C = -5\text{mA}$	82	-	-	-
Emitter-base resistance	R	-	70	100	130	k $\Omega$
Transition frequency	$f_T^{*2}$	$V_{CE} = -10\text{V}, I_E = 5\text{mA}, f = 100\text{MHz}$	-	250	-	MHz

\*1 Each terminal mounted on a reference footprint

\*2 Characteristics of built-in transistor

● Electrical characteristic curves ( $T_a = 25^\circ\text{C}$ )

Fig.1 Grounded emitter propagation characteristics

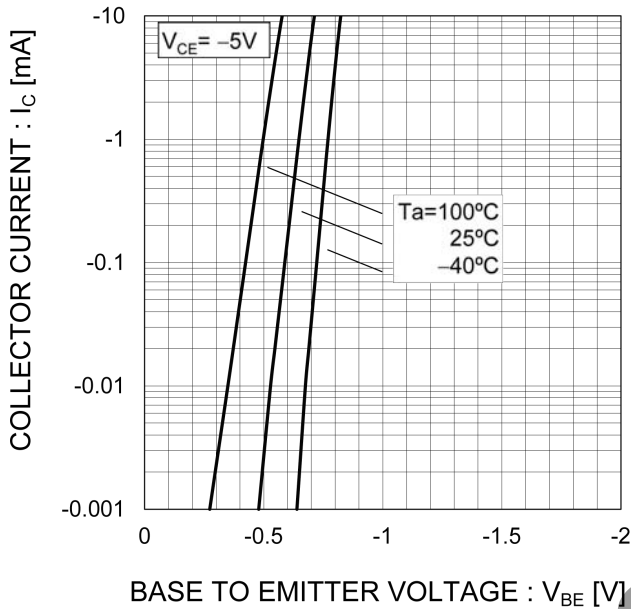


Fig.2 Grounded emitter output characteristics

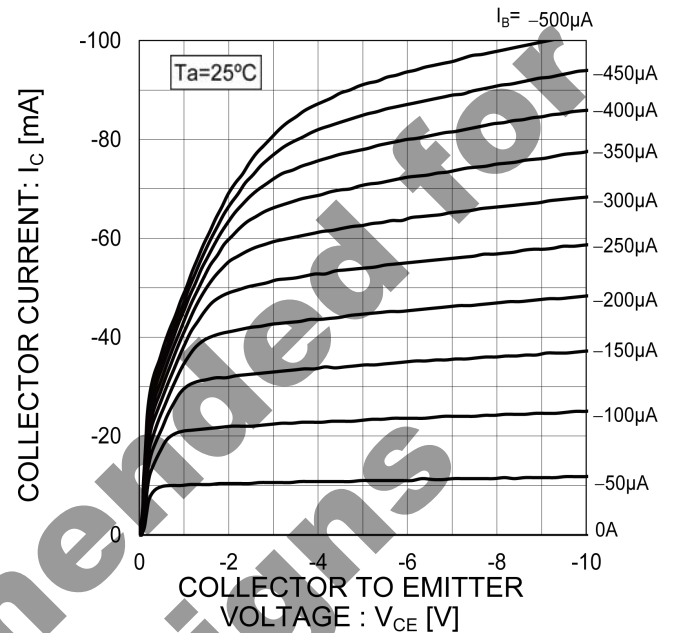


Fig.3 DC Current gain vs. Collector Current

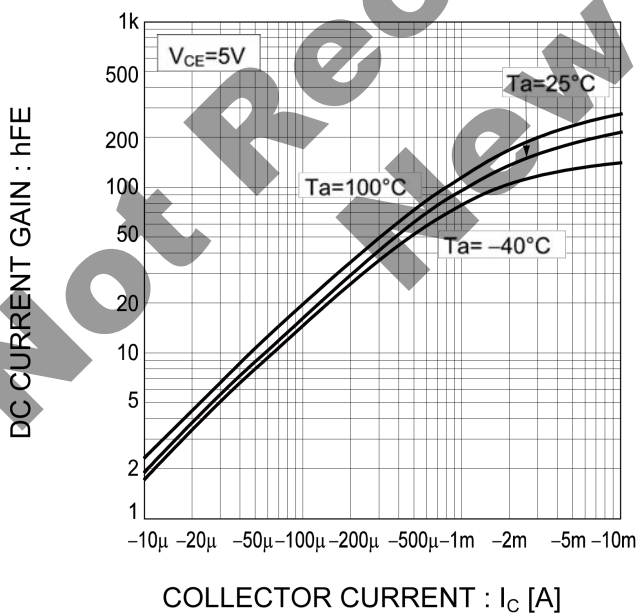
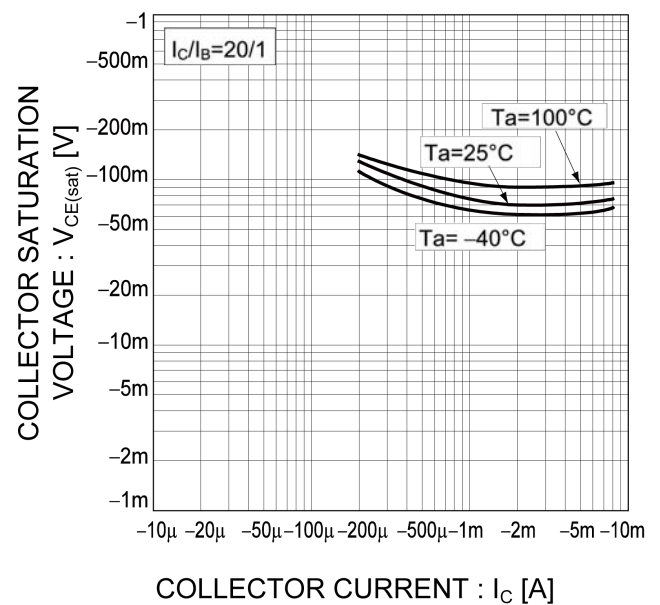
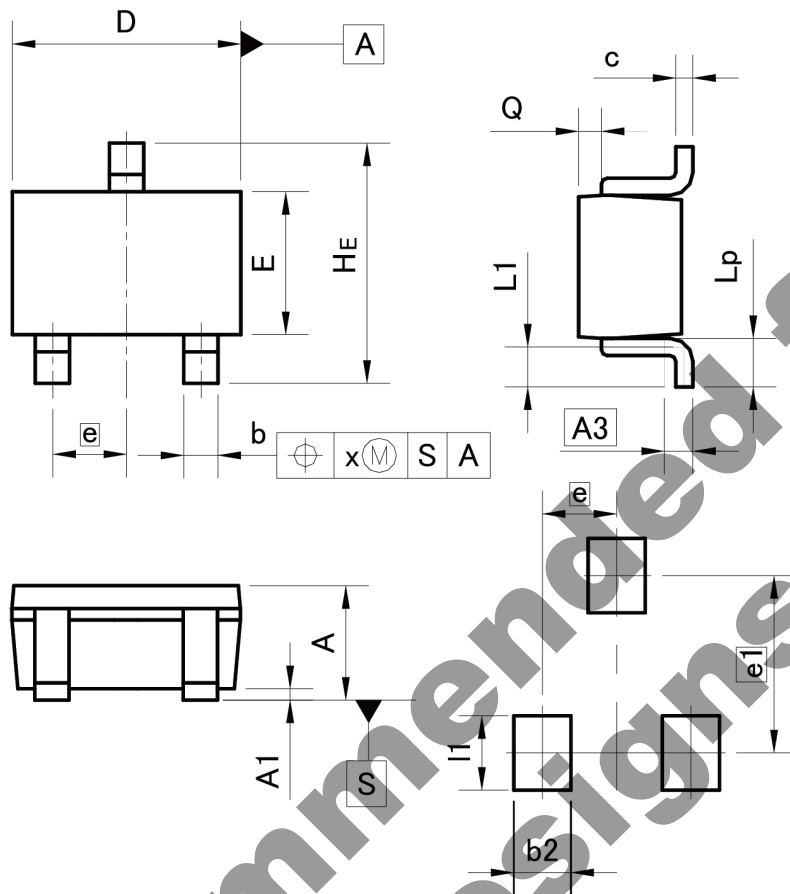


Fig.4 Collector-emitter saturation voltage vs. Collector Current



●Dimensions

UMT3



Pattern of terminal position areas  
[Not a recommended pattern of soldering pads]

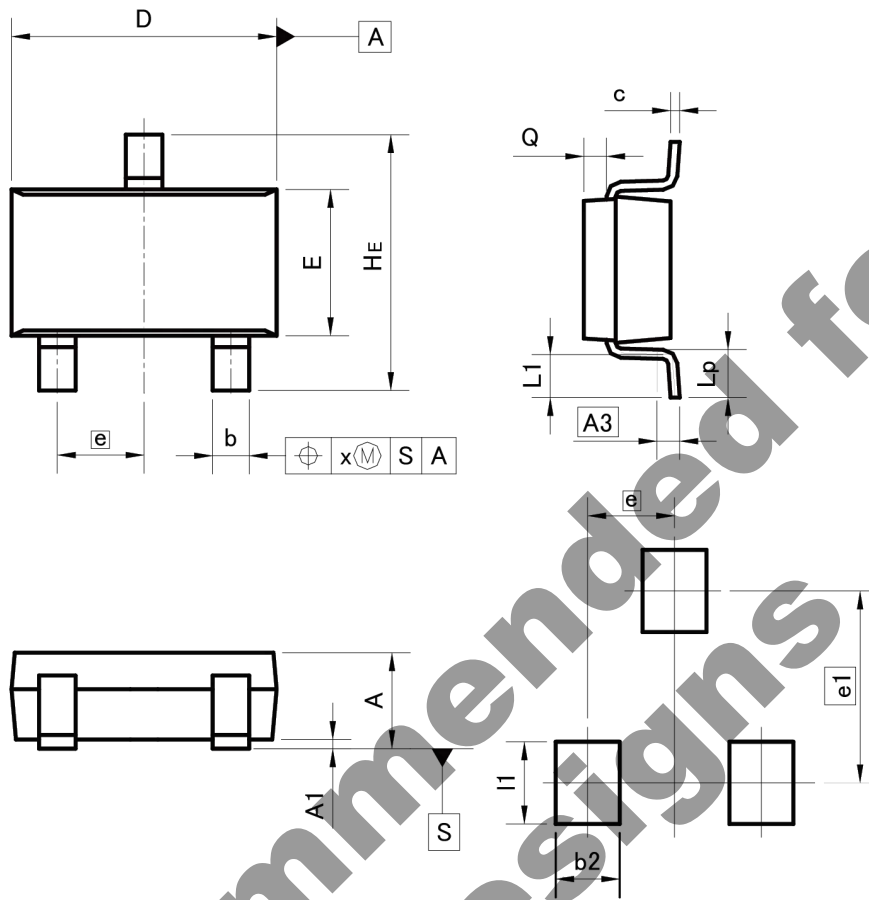
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.15	0.30	0.006	0.012
c	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.026	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
x	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.50	-	0.020
e1	1.55		0.061	
I1	-	0.65	-	0.026

Dimension in mm/inches

●Dimensions

SMT3



Pattern of terminal position areas  
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.35	0.50	0.014	0.020
c	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.037	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.60	-	0.024
e1	2.10		0.083	
l1	-	0.90	-	0.035

Dimension in mm/inches

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